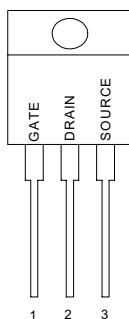
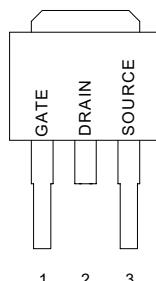
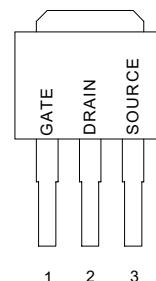


GENERAL DESCRIPTION

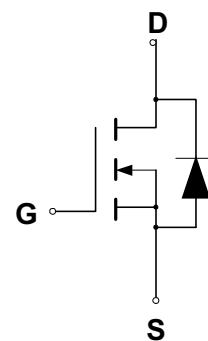
This high voltage MOSFET uses an advanced termination scheme to provide enhanced voltage-blocking capability without degrading performance over time. In addition, this advanced MOSFET is designed to withstand high energy in avalanche and commutation modes. The new energy efficient design also offers a drain-to-source diode with a fast recovery time. Designed for high voltage, high speed switching applications in power supplies, converters and PWM motor controls, these devices are particularly well suited for bridge circuits where diode speed and commutating safe operating areas are critical and offer additional and safety margin against unexpected voltage transients.

FEATURES

- ◆ Robust High Voltage Termination
- ◆ Avalanche Energy Specified
- ◆ Source-to-Drain Diode Recovery Time Comparable to a Discrete Fast Recovery Diode
- ◆ Diode is Characterized for Use in Bridge Circuits
- ◆ I_{DSS} and $V_{DS(on)}$ Specified at Elevated Temperature

PIN CONFIGURATIONTO-220/TO-220FP
Front ViewTO-252
Front ViewTO-251
Front View

N-Channel MOSFET

**ABSOLUTE MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Drain to Current — Continuous	I_D	2.0	A
— Pulsed	I_{DM}	9.0	
Gate-to-Source Voltage — Continue	V_{GS}	± 20	V
— Non-repetitive	V_{GSM}	± 40	V
Total Power Dissipation	P_D		W
TO-251/TO-252		60	
TO-220		60	
TO-220FP		32	
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to 150	°C
Single Pulse Drain-to-Source Avalanche Energy — $T_J = 25^\circ\text{C}$ ($V_{DD} = 100\text{V}$, $V_{GS} = 10\text{V}$, $I_L = 2\text{A}$, $L = 10\text{mH}$, $R_G = 25\Omega$)	E_{AS}	20	mJ
Thermal Resistance — Junction to Case	θ_{JC}	1.0	°C/W
— Junction to Ambient	θ_{JA}	62.5	
Maximum Lead Temperature for Soldering Purposes, 1/8" from case for 10 seconds	T_L	260	°C

ORDERING INFORMATION

Part Number	Package
IRF820-251	TO-251
IRF820-252	TO-252
IRF820-220	TO-220
IRF820-220FP	TO-220 Full Package

ELECTRICAL CHARACTERISTICS

Unless otherwise specified, $T_J = 25^\circ\text{C}$.

Characteristic		IRF820			
		Symbol	Min	Typ	Max
Drain-Source Breakdown Voltage ($V_{GS} = 0 \text{ V}$, $I_D = 250 \mu\text{A}$)		$V_{(BR)DSS}$	600		
Drain-Source Leakage Current ($V_{DS} = 600 \text{ V}$, $V_{GS} = 0 \text{ V}$) ($V_{DS} = 480 \text{ V}$, $V_{GS} = 0 \text{ V}$, $T_J = 125^\circ\text{C}$)		I_{DSS}		0.1 1.0	mA
Gate-Source Leakage Current-Forward ($V_{gsf} = 20 \text{ V}$, $V_{DS} = 0 \text{ V}$)		I_{GSSF}		100	nA
Gate-Source Leakage Current-Reverse ($V_{gsr} = 20 \text{ V}$, $V_{DS} = 0 \text{ V}$)		I_{GSSR}		100	nA
Gate Threshold Voltage ($V_{DS} = V_{GS}$, $I_D = 250 \mu\text{A}$)		$V_{GS(th)}$	2.0		4.0
Static Drain-Source On-Resistance ($V_{GS} = 10 \text{ V}$, $I_D = 1.2\text{A}$) *		$R_{DS(on)}$		4.4	Ω
Forward Transconductance ($V_{DS} \geq 50 \text{ V}$, $I_D = 1.0\text{A}$) *		g_{FS}	1.4		mhos
Input Capacitance	$(V_{DS} = 25 \text{ V}$, $V_{GS} = 0 \text{ V}$, $f = 1.0 \text{ MHz}$)	C_{iss}	435		pF
Output Capacitance		C_{oss}	56		pF
Reverse Transfer Capacitance		C_{rss}	9.2		pF
Turn-On Delay Time	$(V_{DD} = 300 \text{ V}$, $I_D = 2.0 \text{ A}$, $V_{GS} = 10 \text{ V}$, $R_G = 18\Omega$) *	$t_{d(on)}$	12		ns
Rise Time		t_r	21		ns
Turn-Off Delay Time		$t_{d(off)}$	30		ns
Fall Time		t_f	24		ns
Total Gate Charge	$(V_{DS} = 400 \text{ V}$, $I_D = 2.0 \text{ A}$, $V_{GS} = 10 \text{ V}$) *	Q_g	13	22	nC
Gate-Source Charge		Q_{gs}	2.0		nC
Gate-Drain Charge		Q_{gd}	6.0		nC
Internal Drain Inductance (Measured from the drain lead 0.25" from package to center of die)		L_D		4.5	nH
Internal Drain Inductance (Measured from the source lead 0.25" from package to source bond pad)		L_S		7.5	nH
SOURCE-DRAIN DIODE CHARACTERISTICS					
Forward On-Voltage(1)	$(I_S = 2.0 \text{ A}$, $V_{GS} = 0 \text{ V}$, $d_{IS}/dt = 100\text{A}/\mu\text{s}$)	V_{SD}		1.5	V
Forward Turn-On Time		t_{on}		**	ns
Reverse Recovery Time		t_{rr}		340	ns

* Pulse Test: Pulse Width $\leq 300\mu\text{s}$, Duty Cycle $\leq 2\%$

** Negligible, Dominated by circuit inductance

TYPICAL ELECTRICAL CHARACTERISTICS

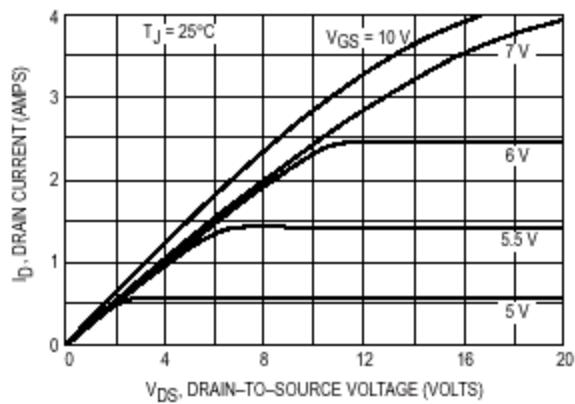


Figure 1. On-Region Characteristics

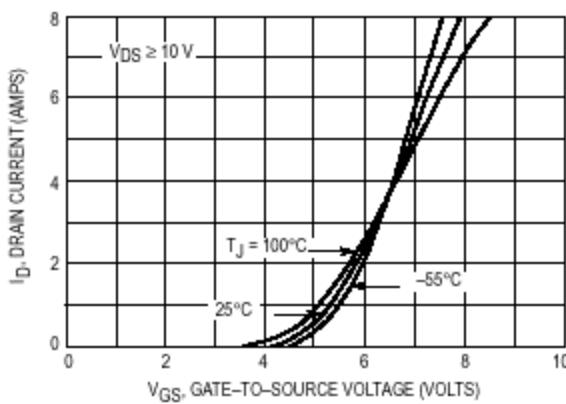


Figure 2. Transfer Characteristics

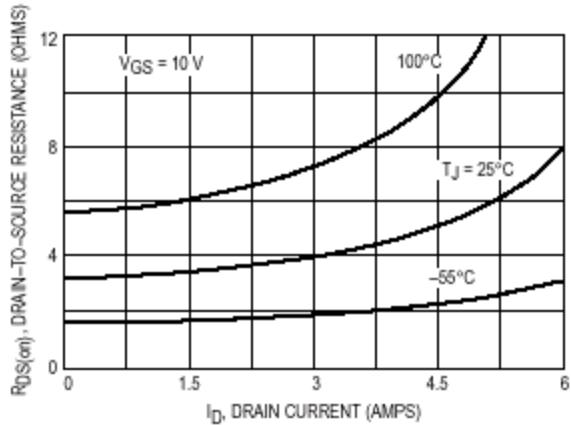


Figure 3. On-Resistance versus Drain Current and Temperature

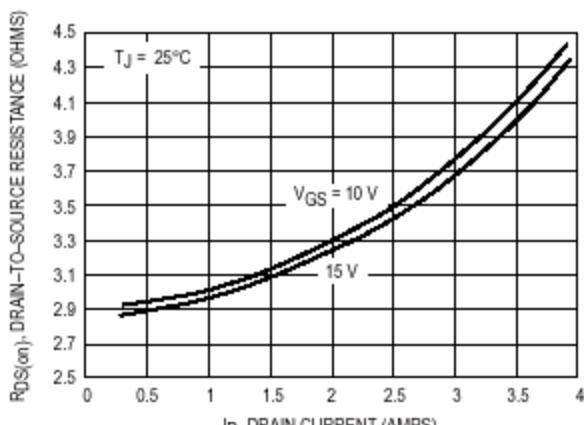


Figure 4. On-Resistance versus Drain Current and Gate Voltage

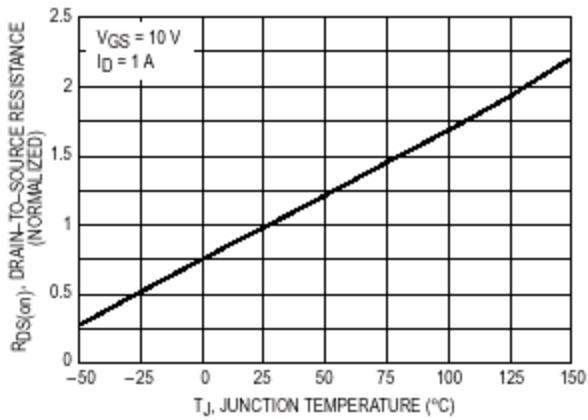


Figure 5. On-Resistance Variation with Temperature

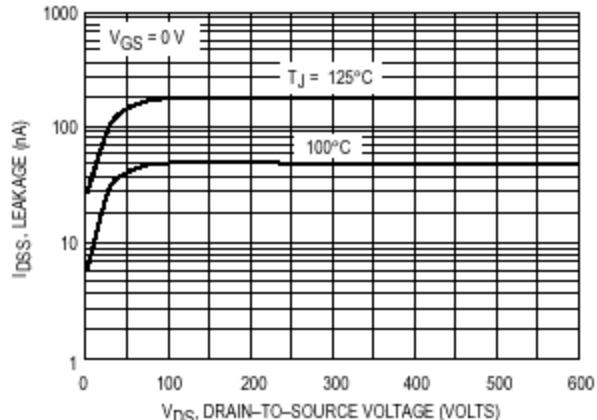
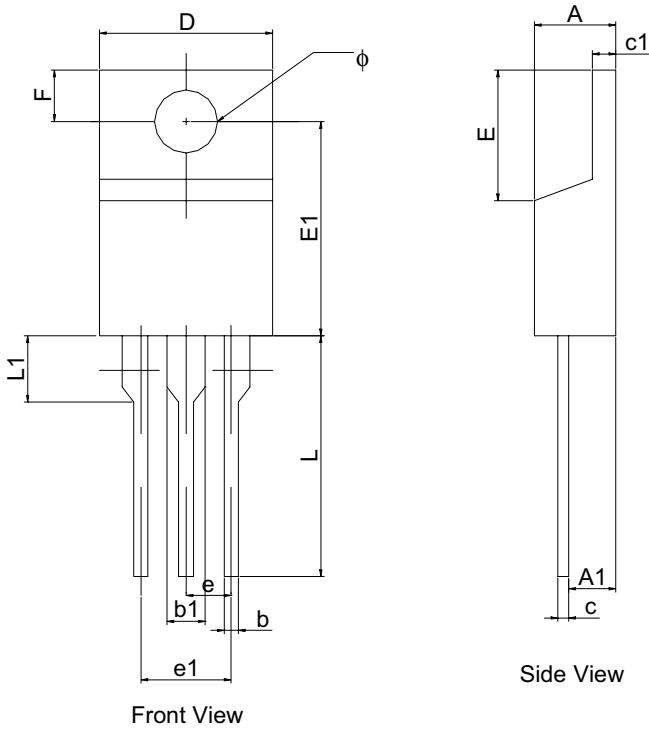
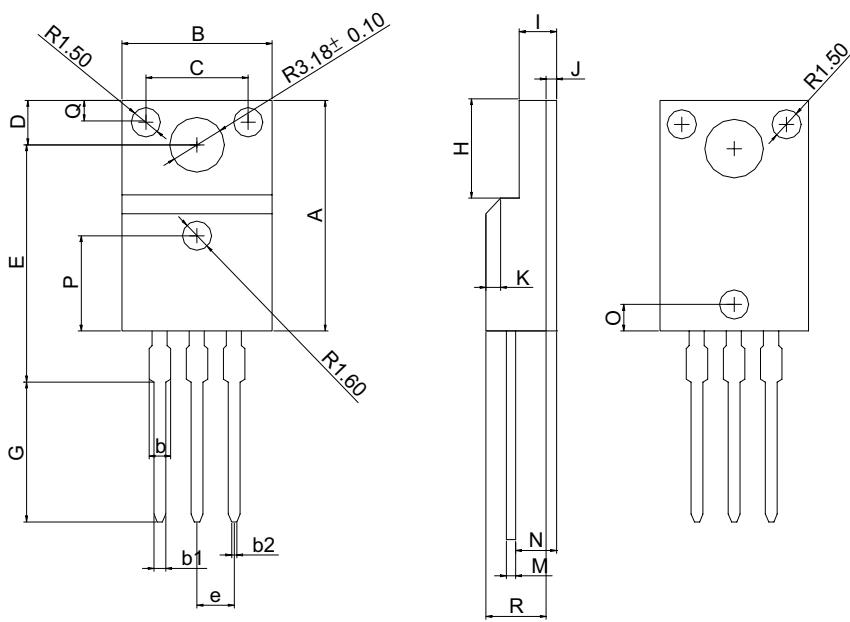


Figure 6. Drain-To-Source Leakage Current versus Voltage

PACKAGE DIMENSION
TO-220

**PIN 1: GATE
PIN 2: DRAIN
PIN 3: SOURCE**

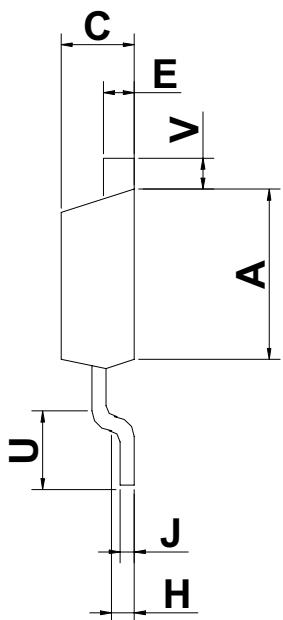
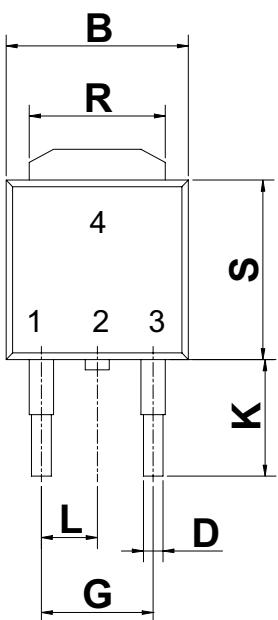
SYMBOLS	DIMENSIONS IN MILLIMETERS			DIMENSIONS IN INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	4.47	---	4.67	0.176	---	0.184
A1	2.52	---	2.82	0.099	---	0.111
b	0.71	---	0.91	0.028	---	0.036
b1	1.17	---	1.37	0.046	---	0.054
c	0.31	---	0.53	0.012	---	0.021
c1	1.17	---	1.37	0.046	---	0.054
D	10.01	---	10.31	0.394	---	0.406
E	8.50	---	8.90	0.335	---	0.350
E1	12.06	---	12.46	0.475	---	0.491
e	---	2.54	---	---	0.100	---
e1	4.98	---	5.18	0.196	---	0.204
F	2.59	---	2.89	0.102	---	0.114
L	13.40	---	13.80	0.528	---	0.543
L1	3.56	---	3.96	0.140	---	0.156
φ	3.79	---	3.89	0.149	---	0.153

TO-220FP


SYMBOLS	DIMENSIONS IN MILLIMETERS			DIMENSIONS IN INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	15.67	---	16.07	0.617	---	0.633
B	9.96	---	10.36	0.392	---	0.408
C	---	7.00	---	---	0.275	---
D	3.20	---	3.40	0.126	---	0.134
E	15.60	---	16.00	0.614	---	0.630
G	9.45	---	10.05	0.372	---	0.396
H	6.48	---	6.88	0.255	---	0.279
I	2.34	---	2.74	0.092	---	0.108
J	---	0.70	---	---	0.028	---
K	---	1.00	---	---	0.039	---
M	0.45	---	0.60	0.018	---	0.024
N	2.56	---	2.96	0.101	---	0.117
O	---	1.80	---	---	0.071	---
P	---	6.50	---	---	0.256	---
Q	---	1.50	---	---	0.059	---
R	4.50	---	4.90	0.177	---	0.193
b	---	---	1.47	---	---	0.058
b1	0.70	---	0.90	0.028	---	0.035
b2	0.25	---	0.45	0.010	---	0.018
e	---	2.54	---	---	0.100	---

PACKAGE DIMENSION

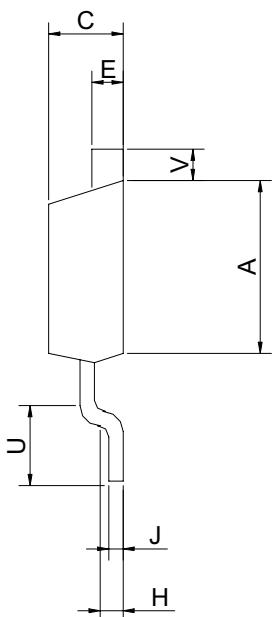
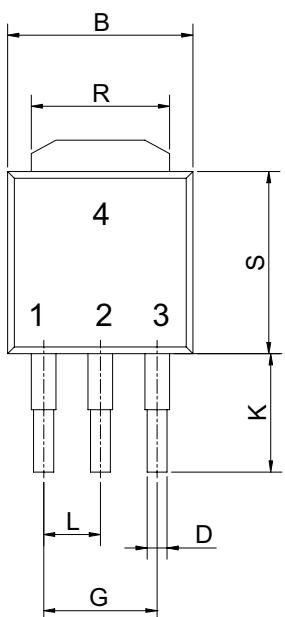
TO-252



PIN 1: GATE
PIN 2: DRAIN
PIN 3: SOURCE

SYMBOLS	DIMENSIONS IN MILLIMETERS			DIMENSIONS IN INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	5.97	---	6.35	0.235	---	0.250
B	6.35	---	6.73	0.250	---	0.265
C	2.19	---	2.38	0.086	---	0.094
D	0.69	---	0.88	0.027	---	0.035
E	0.84	---	1.01	0.033	---	0.047
G	4.58BSC			0.180BSC		
H	0.87	---	1.01	0.034	---	0.040
J	0.46	---	0.58	0.018	---	0.023
K	2.60	---	2.89	0.102	---	0.114
L	2.29BSC			0.090BSC		
R	4.45	---	5.46	0.175	---	0.215
S	0.51	---	1.27	0.020	---	0.050
U	0.51	---	---	0.020	---	---
V	0.77	---	1.27	0.030	---	0.050

TO-251



PIN 1: GATE
PIN 2: DRAIN
PIN 3: SOURCE

SYMBOLS	DIMENSIONS IN MILLIMETERS			DIMENSIONS IN INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	5.97	---	6.35	0.235	---	0.250
B	6.35	---	6.73	0.250	---	0.265
C	2.19	---	2.38	0.086	---	0.094
D	0.69	---	0.88	0.027	---	0.035
E	0.84	---	1.01	0.033	---	0.047
G	4.58BSC			0.180BSC		
H	0.87	---	1.01	0.034	---	0.040
J	0.46	---	0.58	0.018	---	0.023
K	2.60	---	2.89	0.102	---	0.114
L	2.29BSC			0.090BSC		
R	4.45	---	5.46	0.175	---	0.215
S	0.51	---	1.27	0.020	---	0.050
U	0.51	---	---	0.020	---	---
V	0.77	---	1.27	0.030	---	0.050